



# THD215HI

## HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY
- U.L. RECOGNISED ISOWATT218 PACKAGE (U.L. FILE # E81734 (N)).

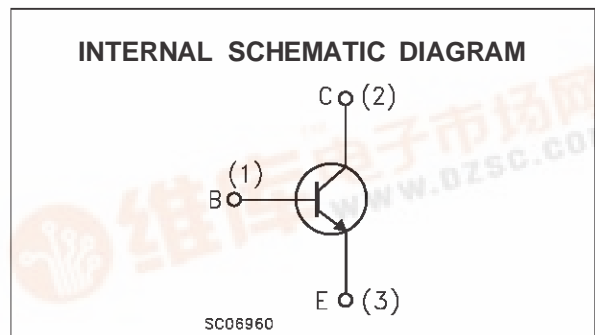
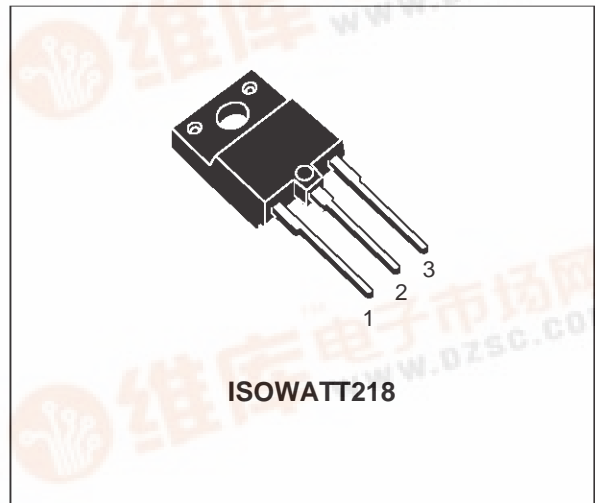
### APPLICATIONS

- HORIZONTAL DEFLECTION FOR COLOUR TV AND MONITORS

### DESCRIPTION

This device is manufactured using Multi-epitaxial Mesa technology for cost-effective high performance and uses a Hollow Emitter structure to enhance switching speeds.

The THD series is designed for use in horizontal deflection circuits in televisions and monitors.



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage ( $I_E = 0$ )	1500	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	700	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	10	V
$I_C$	Collector Current	10	A
$I_{CM}$	Collector Peak Current ( $t_p < 5$ ms)	20	A
$I_B$	Base Current	5	A
$I_{BM}$	Base Peak Current ( $t_p < 5$ ms)	10	A
$P_{tot}$	Total Dissipation at $T_c = 25$ °C	57	W
$T_{stg}$	Storage Temperature	-65 to 150	°C
$T_j$	Max. Operating Junction Temperature	150	°C



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## THERMAL DATA

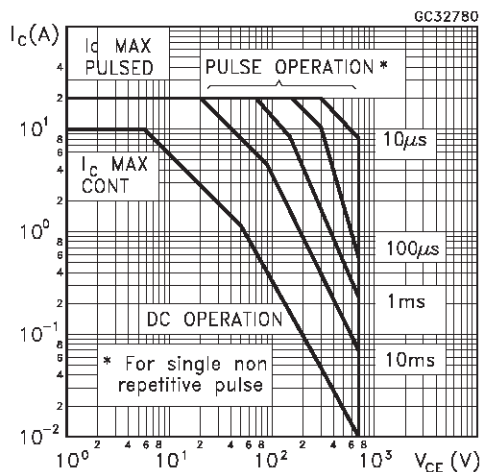
$R_{thj-case}$	Thermal Resistance Junction-case	Max	2.2	$^{\circ}C/W$
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## ELECTRICAL CHARACTERISTICS ( $T_{case} = 25^{\circ}C$ unless otherwise specified)

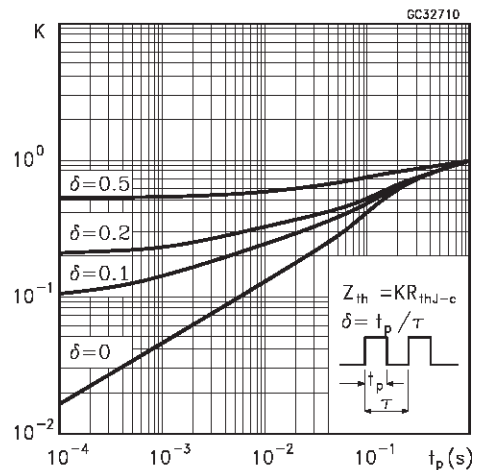
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CEO}$	Collector Cut-off Current ( $I_B = 0$ )	$V_{CE} = 700 V$			10	$\mu A$
$I_{CES}$	Collector Cut-off Current ( $V_{BE} = 0$ )	$V_{CE} = 1500 V$			10	$\mu A$
$I_{EBO}$	Emitter Cut-off Current ( $I_C = 0$ )	$V_{EB} = 5 V$			100	$\mu A$
$V_{CEO(sus)}^*$	Collector-Emitter Sustaining Voltage ( $I_B = 0$ )	$I_C = 100 mA$	700			V
$V_{CE(sat)}^*$	Collector-Emitter Saturation Voltage	$I_C = 6 A$ $I_B = 1.2 A$			1.3	V
$V_{BE(sat)}^*$	Base-Emitter Saturation Voltage	$I_C = 6 A$ $I_B = 1.2 A$			1.3	V
$h_{FE}^*$	DC Current Gain	$I_C = 10 mA$ $V_{CE} = 5 V$ $I_C = 6 A$ $V_{CE} = 5 V$ $I_C = 6 A$ $V_{CE} = 5 V$ $T_j = 125^{\circ}C$	10 6 4		13	
$t_s$ $t_f$	INDUCTIVE LOAD Storage Time Fall Time	$I_C = 4.5 A$ $f = 64 KHz$ $I_{B1} = 1.5 A$ $I_{B2} = -2.4 A$ $V_{ceflyback} = 1100 \sin\left(\frac{\pi}{5} 10^6\right) t$ V		3.3 160		$\mu s$ ns

\* Pulsed: Pulse duration = 300  $\mu s$ , duty cycle 1.5 %

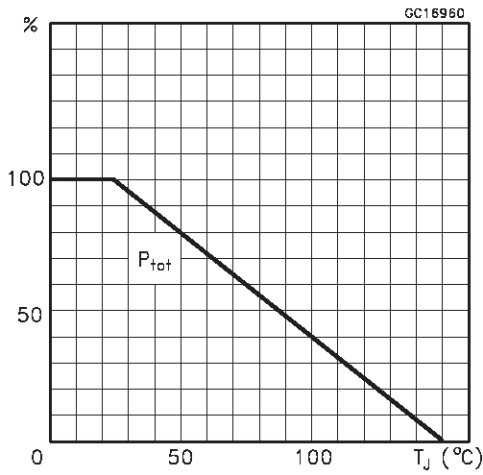
## Safe Operating Area



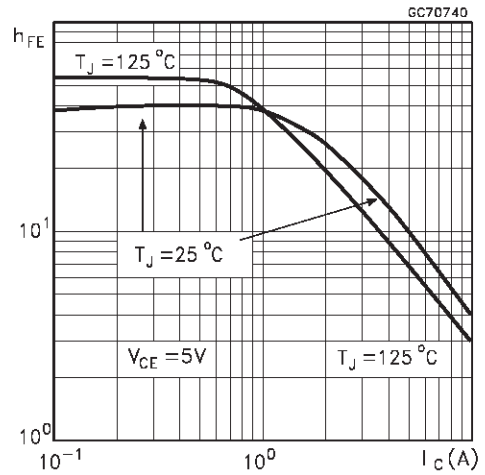
## Thermal Impedance



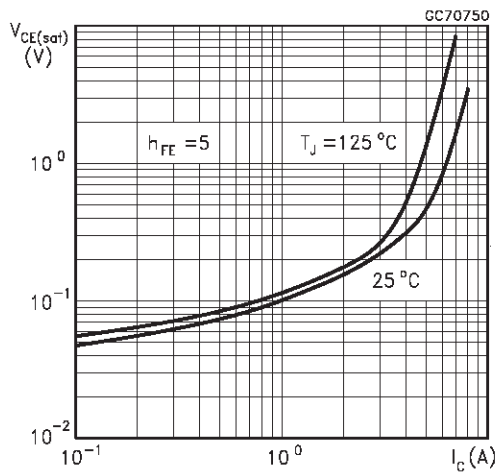
Derating Curve



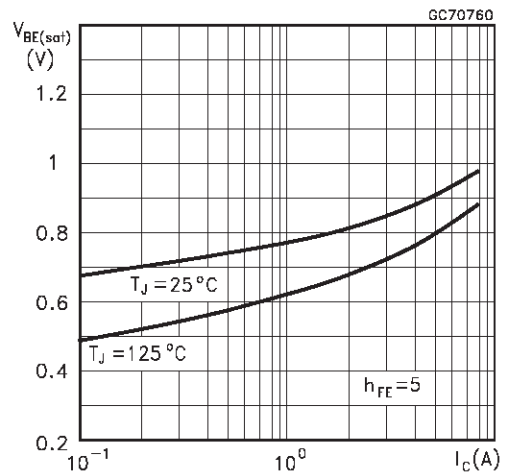
DC Current Gain



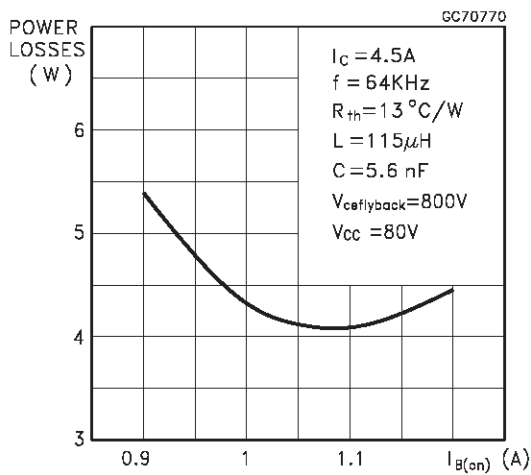
Collector Emitter Saturation Voltage



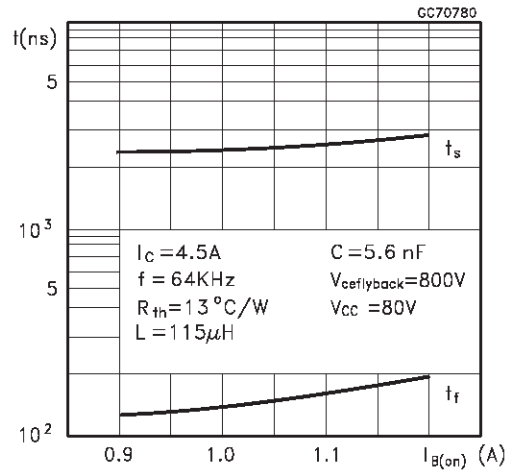
Base Emitter Saturation Voltage



Power Losses at 64 KHz



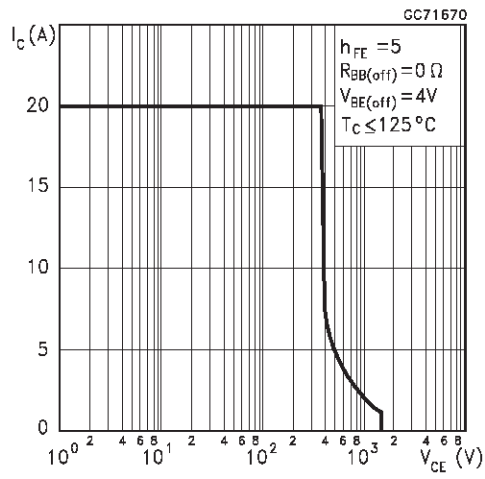
Switching Time Inductive Load at 64 KHz



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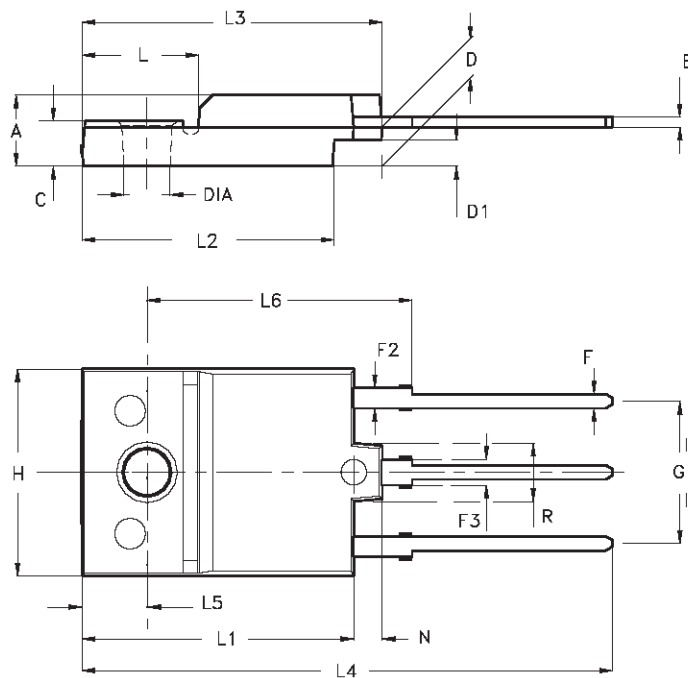
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## Reverse Biased SOA



**ISOWATT218 MECHANICAL DATA**

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	5.35		5.65	0.211		0.222
C	3.30		3.80	0.130		0.150
D	2.90		3.10	0.114		0.122
D1	1.88		2.08	0.074		0.082
E	0.75		0.95	0.030		0.037
F	1.05		1.25	0.041		0.049
F2	1.50		1.70	0.059		0.067
F3	1.90		2.10	0.075		0.083
G	10.80		11.20	0.425		0.441
H	15.80		16.20	0.622		0.638
L		9			0.354	
L1	20.80		21.20	0.819		0.835
L2	19.10		19.90	0.752		0.783
L3	22.80		23.60	0.898		0.929
L4	40.50		42.50	1.594		1.673
L5	4.85		5.25	0.191		0.207
L6	20.25		20.75	0.797		0.817
N	2.1		2.3	0.083		0.091
R		4.6			0.181	
DIA	3.5		3.7	0.138		0.146



- Weight : 4.9 g (typ.)
- Maximum Torque (applied to mounting flange) Recommended 0.8 Nm; Maximum: 1 Nm
- The side of the dissipator must be flat within 80 μm

P025C/A

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